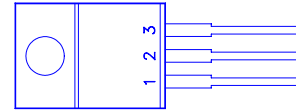
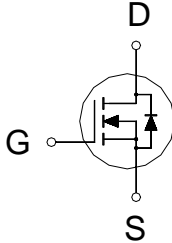


**PRODUCT SUMMARY**

|               |              |       |
|---------------|--------------|-------|
| $V_{(BR)DSS}$ | $R_{DS(ON)}$ | $I_D$ |
| 25            | 20m          | 45A   |



1. GATE
2. DRAIN
3. SOURCE

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**ABSOLUTE MAXIMUM RATINGS ( $T_C = 25\text{ }^\circ\text{C}$  Unless Otherwise Noted)**

| PARAMETERS/TEST CONDITIONS   |                                   | SYMBOL         | LIMITS     | UNITS            |
|--|-----------------------------------|----------------|------------|------------------|
| Gate-Source Voltage  |                                   | $V_{GS}$       | $\pm 20$   | V                |
| Continuous Drain Current   | $T_C = 25\text{ }^\circ\text{C}$  | $I_D$          | 45         | A                |
|  | $T_C = 100\text{ }^\circ\text{C}$ |                | 28         |                  |
| Pulsed Drain Current <sup>1</sup>  |                                   | $I_{DM}$       | 140        |                  |
| Avalanche Current  |                                   | $I_{AR}$       | 20         | mJ               |
| Avalanche Energy   | $L = 0.1\text{mH}$                | $E_{AS}$       | 140        |                  |
| Repetitive Avalanche Energy <sup>2</sup>                                 | $L = 0.05\text{mH}$               | $E_{AR}$       | 5.6        |                  |
| Power Dissipation  | $T_C = 25\text{ }^\circ\text{C}$  | $P_D$          | 65         | W                |
|  | $T_C = 100\text{ }^\circ\text{C}$ |                | 33         |                  |
| Operating Junction & Storage Temperature Range                           |                                   | $T_j, T_{stg}$ | -55 to 150 | $^\circ\text{C}$ |
| Lead Temperature ( <sup>1</sup> / <sub>16</sub> " from case for 10 sec.) |                                   | $T_L$          | 275        |                  |

**THERMAL RESISTANCE RATINGS**

| THERMAL RESISTANCE  | SYMBOL          | TYPICAL | MAXIMUM | UNITS                       |
|---------------------|-----------------|---------|---------|-----------------------------|
| Junction-to-Case    | $R_{\theta JC}$ |         | 3       | $^\circ\text{C} / \text{W}$ |
| Junction-to-Ambient | $R_{\theta JA}$ |         | 70      |                             |
| Case-to-Heatsink    | $R_{\theta CS}$ | 0.7     |         |                             |

<sup>1</sup>Pulse width limited by maximum junction temperature.

<sup>2</sup>Duty cycle  $\leq 1\%$

**ELECTRICAL CHARACTERISTICS ( $T_C = 25\text{ }^\circ\text{C}$ , Unless Otherwise Noted)**

| PARAMETER                       | SYMBOL        | TEST CONDITIONS  | LIMITS |     |           | UNIT          |
|---------------------------------|---------------|--|--------|-----|-----------|---------------|
|                                 |               |  | MIN    | TYP | MAX       |               |
| <b>STATIC</b>                   |               |  |        |     |           |               |
| Drain-Source Breakdown Voltage  | $V_{(BR)DSS}$ | $V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$                                 | 25     |     |           | V             |
| Gate Threshold Voltage          | $V_{GS(th)}$  | $V_{DS} = V_{GS}, I_D = 250\mu\text{A}$                                    | 0.8    | 1.2 | 2.5       |               |
| Gate-Body Leakage               | $I_{GSS}$     | $V_{DS} = 0\text{V}, V_{GS} = \pm 20\text{V}$                              |        |     | $\pm 250$ | nA            |
| Zero Gate Voltage Drain Current | $I_{DSS}$     | $V_{DS} = 20\text{V}, V_{GS} = 0\text{V}$                                  |        |     | 25        | $\mu\text{A}$ |
|                                 |               | $V_{DS} = 20\text{V}, V_{GS} = 0\text{V}, T_J = 125\text{ }^\circ\text{C}$ |        |     | 250       |               |

|   |              |                              |    |    |    |   |
|---|--------------|------------------------------|----|----|----|---|
| On-State Drain Current <sup>1</sup>           | $I_{D(ON)}$  | $V_{DS} = 10V, V_{GS} = 10V$ | 45 |    |    | A |
| Drain-Source On-State Resistance <sup>1</sup> | $R_{DS(ON)}$ | $V_{GS} = 7V, I_D = 18A$     |    | 20 | 30 | m |
|   |              | $V_{GS} = 10V, I_D = 20A$    |    | 15 | 28 |   |
| Forward Transconductance <sup>1</sup>         | $g_{fs}$     | $V_{DS} = 15V, I_D = 30A$    |    | 16 |    | S |

**DYNAMIC**

|                                  |              |  |  |     |  |    |
|----------------------------------|--------------|--|--|-----|--|----|
| Input Capacitance                | $C_{iss}$    | $V_{GS} = 0V, V_{DS} = 15V, f = 1MHz$                                  |  | 600 |  | pF |
| Output Capacitance               | $C_{oss}$    |  |  | 290 |  |    |
| Reverse Transfer Capacitance     | $C_{rss}$    |  |  | 100 |  |    |
| Total Gate Charge <sup>2</sup>   | $Q_g$        | $V_{DS} = 0.5V_{(BR)DSS}, V_{GS} = 10V,$<br>$I_D = 20A$                |  | 25  |  | nC |
| Gate-Source Charge <sup>2</sup>  | $Q_{gs}$     |  |  | 2.9 |  |    |
| Gate-Drain Charge <sup>2</sup>   | $Q_{gd}$     |  |  | 7.0 |  |    |
| Turn-On Delay Time <sup>2</sup>  | $t_{d(on)}$  | $V_{DS} = 15V, R_L = 1$<br>$I_D \cong 30A, V_{GS} = 10V, R_{GS} = 2.5$ |  | 7.0 |  | nS |
| Rise Time <sup>2</sup>           | $t_r$        |  |  | 7.0 |  |    |
| Turn-Off Delay Time <sup>2</sup> | $t_{d(off)}$ |  |  | 24  |  |    |
| Fall Time <sup>2</sup>           | $t_f$        |  |  | 6.0 |  |    |

**SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS (T<sub>C</sub> = 25 °C)**

|                               |               |                                     |  |       |     |         |
|-------------------------------|---------------|-------------------------------------|--|-------|-----|---------|
| Continuous Current            | $I_S$         |                                     |  |       | 45  | A       |
| Pulsed Current <sup>3</sup>   | $I_{SM}$      |                                     |  |       | 150 |         |
| Forward Voltage <sup>1</sup>  | $V_{SD}$      | $I_F = I_S, V_{GS} = 0V$            |  |       | 1.3 | V       |
| Reverse Recovery Time         | $t_{rr}$      | $I_F = I_S, di_F/dt = 100A / \mu S$ |  | 37    |     | nS      |
| Peak Reverse Recovery Current | $I_{RM(REC)}$ |                                     |  | 200   |     | A       |
| Reverse Recovery Charge       | $Q_{rr}$      |                                     |  | 0.043 |     | $\mu C$ |

<sup>1</sup>Pulse test : Pulse Width ≤ 300 μsec, Duty Cycle ≤ 2%.

<sup>2</sup>Independent of operating temperature.

<sup>3</sup>Pulse width limited by maximum junction temperature.

**REMARK: THE PRODUCT MARKED WITH “P45N03LTG”, DATE CODE or LOT #**

**Orders for parts with Lead-Free plating can be placed using the PXXXXXXG parts name.**

**TO-220 (3-Lead) MECHANICAL DATA**

| Dimension | mm   |       |       | Dimension | mm   |      |      |
|-----------|------|-------|-------|-----------|------|------|------|
|           | Min. | Typ.  | Max.  |           | Min. | Typ. | Max. |
| A         | 9.78 | 10.16 | 10.54 | H         | 2.4  | 2.54 | 2.68 |
| B         | 2.61 | 2.74  | 2.87  | I         | 1.19 | 1.27 | 1.35 |
| C         |      | 20    |       | J         | 4.4  | 4.6  | 4.8  |
| D         | 28.5 | 28.9  | 29.3  | K         | 1.14 | 1.27 | 1.4  |
| E         | 14.6 | 15.0  | 15.4  | L         | 2.3  | 2.6  | 2.9  |
| F         | 8.4  | 8.8   | 9.2   | M         | 0.26 | 0.46 | 0.66 |
| G         | 0.72 | 0.8   | 0.88  | N         |      | 7°   |      |

